

Surface Mount Schottky Barrier rectifiers

Using the Schottky Barrier principle with a Molybdenum barrier meta. These state-of-the-art geometry features epitaxial construction with oxide passivation and metal overlay contact. Ideally suited for low voltage, high frequency rectification, or as free wheeling and polarity protection diodes, in surface mount applications where compact size and weight are critical to the system.

Features

- *Low Forward Voltage.
- *Low Switching noise.
- * High Current Capacity
- * Guarantee Reverse Avalanche.
- * Guard-Ring for Stress Protection.
- *Low Power Loss & High efficiency.
- *****150° C Operating Junction Temperature
- *Low Stored Charge Majority Carrier Conduction.
- * Plastic Material used Carries Underwriters Laboratory Flammability Classification 94V-O
- * Moisture Sensitivity Level: MSL-1



* In compliance with EU RoHs 2002/95/EC directives

MAXIMUM RATINGS

Characteristic	Symbol	SM17	SM18	SM19	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	20	30	40	V
RMS Reverse Voltage	VR _(RMS)	14	21	28	V
Average Rectifier Forward Current	Io	1.0		Α	
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions half-wave, single phase,60Hz)	I _{FSM}	25		А	
Operating and Storage Junction Temperature Range	T_J , T_{STG}	-65 to +150		$^{\circ}$	

ELECTRIAL CHARACTERISTICS

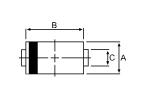
ELECTRIAL CHARACTERIOTICS						
Characteristic	Symbol	SM17	SM18	SM19	Unit	
Maximum Instantaneous Forward Voltage (I _F =1.0 Amp) (I _F =3.0 Amp)	V _F	0.45 0.75	0.: 0.:		>	
Maximum Instantaneous Reverse Current (Rated DC Voltage, $T_C = 25^{\circ}C$) (Rated DC Voltage, $T_C = 125^{\circ}C$)	I _R	0.5 10		mA		
Maximum Thermal Resistance Junction to Case	$R_{ heta JC}$	60		°C/W		
Typical Junction Capacitance (Reverse Voltage of 4 volts & f=1 MHz)	C_P	90	8	0	pF	

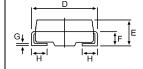
SCHOTTKY BARRIER RECTIFIERS

1.0 AMPERES 20-40 VOLTS



DO-214AC(SMA)





DIM	MILLIMETERS			
DIIVI	MIN	MAX		
Α	2.20	2.80		
В	4.10	4.70		
С	1.30	1.70		
D	4.70	5.30		
Е	1.90	2.50		
F		1.30		
G		0.30		
Н	0.95	1.50		

CASE---

Transfer molded plastic

OLARITY---Cathode indicated polarity band



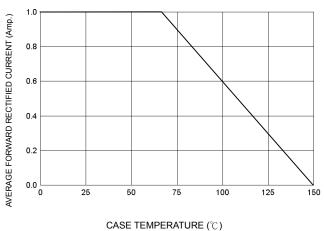


FIG-2 TYPICAL FORWARD CHARACTERISITICS

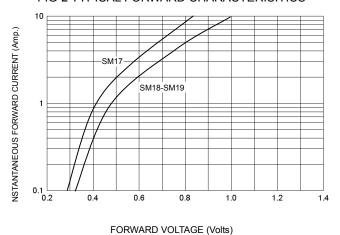


FIG-3 TYPICAL REVERSE CHARACTERISTICS

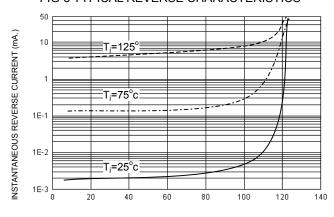
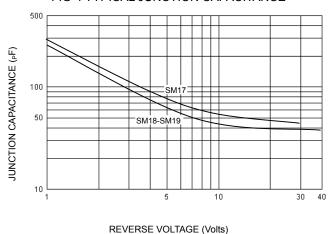
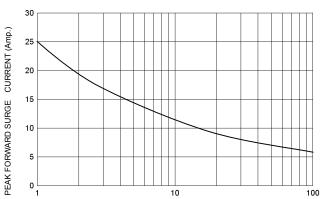


FIG-4 TYPICAL JUNCTION CAPACITANCE



PERCENT OF RATED REVERSE VOLTAGE (%)

FIG-5 PEAK FORWARD SURGE CURRENT



NUMBER OF CYCLES AT 60 Hz



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